



Revision 1.11

GAIN CHIPS AR coated Fabry-Perot Laser





General Product Information

Product	Application
tunable 840 nm Fabry-Perot Laser	Spectroscopy
for use in an External Cavity Diode Laser (ECDL)	Covering popular wavelengths
sealed SOT Housing	between 810 and 860 nm
Monitor Diode	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-20		50
Forward Current	I _F	mA			200
Reverse Voltage	V_R	V			0
Output Power (extracavity)	P _{opt}	mW			100

Measurement Conditions / Comments

Stess in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		40
Forward Current	I_{F}	mA			180

Measurement Conditions / Comments
Wedsarement Conditions / Comments

Characteristics at T_{LD}= 25 °C at BOL, with external cavity under recommended working condition

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm		840	
Tuning Range	$\Delta \lambda_{tun}$	nm	810		860
Output Power	P_{opt}	mW		50	
Polarization				TE	
Output Power	P_{opt}	W		50	
Spatial Mode (transversal)				TEM00	

Measurement Conditions / Comments

The actual achieved wavelength and power are strongly influenced by the external cavity. eyP gives no guarantee on these parameters.

E field parallel to Pin 2 - Pin 3 - plane

Fundamental Mode





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Amplified Spontaneous Emission (ASE) without external cavity

Parameter	Symbol	Unit	min	typ	max
Divergence parallel (FWHM)	$\Theta_{ }$			10	
Divergence perpendicular (FWHM)	Θ_{\perp}			23	
Monitor Detector Responsivity	I_{mon} / P_{ASE}	μΑ/mW	1		40

Measurement Conditions / Comments
parallel to Pin 2 - Pin 3 plane (see p. 3)
perpendicular to Pin 2 - Pin 3 plane (see p. 3)
$U_{RMD} = 5 \text{ V}$

Chip Parameter

Parameter	Symbol	Unit	min	typ	max
Cavity Length	L	μm		1500	
Reflectivity at Front Facet	R_{ff}			3·10 ⁻⁴	1·10 ⁻³

Measurement Conditions / Comments			



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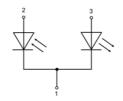
Package Dimensions

Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h	mm	3.50	3.65	3.70
Excentricity of Emission Center	R	mm			0.12
Pin Length	L_{PIN}	mm		14	

Measurement Conditions / Comments reference plane: top side of TO header reference: center of outer diameter of header

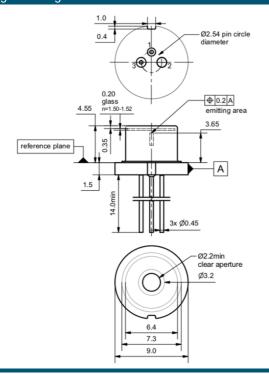
Package Pinout

- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode





Package Drawings





AIZ-16-0421-1517

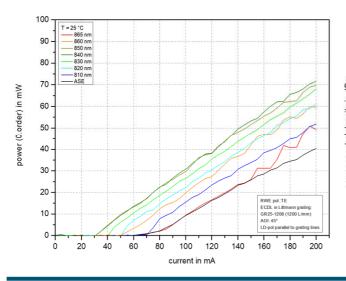


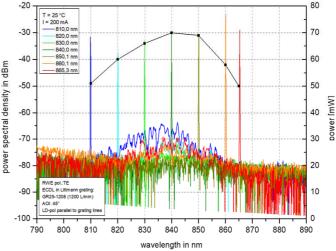
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Typical Measurement Results





Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPA diode type is known to be sensitive against thermal stress. It should not be operated without appropriate injection from a seed laser. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode. The chip should be protected against moisture. A water vapor content below 5000 ppm is recommended for applications with high reliability requirements.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.







INVISIBLE LASER RADIATION AVOID EYE OR SKIN EXPOSURE TO DIRECT OR SCATTERED RADIATION CLASS 4 LASER PRODUCT WAVELENGTH 840 nm MAX. OUTPUT POWER 100 mW







